

# L6287

# POWER COMBO DRIVER

PRELIMINARY DATA

#### DESCRIPTION

The F-VHS Motor Driver COMBO IC includes a double three phase brushless motor driver plus a DC full bridge motor driver for VCR application.

The package is SDIP42 (38+2+2 pin ground frame).

The device is realized in BCD technology with power LDMOS output stages.

The gate drive for high side stages is provided by an internal charge pump with two external capacitors. The first three phase motor driver is devoted to the DRUM motor control.

The phase sequence update signal is provided initially by an external start-up signal (FSTART), whose frequency is internally divided by four, while, during normal operation, is provided by an optical tacho converter signal.

This signal is used as clock and reset for the state machine.

The regulation of the speed is externally provided by means of PWM signal generated by the  $\mu$ P (DPWM), without external sensing resistor. The feedback to the  $\mu$ P unit is given by a suitable open drain output signal (PUD) synchronized by the internal state machine.

The second three phase motor driver is devoted to the CAPSTAN control. While the DRUM will always spin in a fixed direction, the CAPSTAN motor needs a more sophisticated logic to control the changes in spin direction.

The motor position detection is carried out by means of three comparators for Hall effect sensors. The loop regulation for this motor is still provided by the  $\mu$ P with the signals CPWM and CDIR.

The LOADING motor section include a full bridge DC motor driver. The motor operations are directly set by the inputs LPWM, LDIR according to the truth table reported on the page 5.

The device also includes a circuit for early thermal alarm, last thermal alarm and thermal shutdown with hysteresys. The output of this stage is an open drain, kept ON during normal operations.

The THERM signal follows the inverted FSTART signal between early warning and last warning temperature, while remains in high impedance (OFF) after lastwarning temperature and during thermal shutdown.



The STANDBY state of the device is imposed by

- THERMAL SHUTDOWN
- UNDERVOLTAGE ON VCC SUPPLY
- EXTERNAL SIGNAL FSTART;

This state is imposed automatically after a defined time-out.

The time-out is realized by sensing the falling edges of the FSTART signal: if no edges are recorded for a time interval greater than a certain time constant, the STANDBY condition is generated.

The time constant is defined by the external capacitor CTO.

In the STANDBY state the main functions (upper power stages, opto decoder, etc) of the device are turned off in order to minimize the power consumption.

The device also implement a HEATER function. The HEATER transistor is OFF during thermal shutdown, undervoltage condition and during normal working mode.

The HEATER transistor is driven ON when the external STANDBY condition is present according to the following table:

FSTART	HIGH	LOW
HEATER	OFF	ON

During the ON condition, the specified heater Ron is not guaranteed if all the voltage supplies are not at their minimum nominal value.

#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
V <sub>DD</sub>	Drum Supply Voltage	20	V (**)
VDC	Capstan Supply Voltage	20	V (**)
V <sub>DL</sub>	Loading Supply Voltage	20	V (**)
UPPER POWER VDS MAX	Motor Output to Ground Voltage	20	V(***)
LOWERPOWER	Motor Output to Supply Voltage	20	V (***)
Vcc	Logic Supply Voltage	7	V
Vs	Special Supply Voltage	7	V
lp1	Loading Motor Peak Current ( $T_{on} = 1\mu s$ Duty Cycle = 2%)	1.6	А
lpd	Drum Motor Peak Current (Ton = 1µs Duty Cycle = 2%)	1.4	А
lpc	Capstan Motor Peak Current (Ton = 1µs Duty Cycle = 2%)	1.8	A
Vil	Logic Input Low State Voltage	-0.1	V
Vih	Logic Input High StateVoltage	7	V
Vtherm	Open Drain Maximum Voltage	7	V
Vheat	Open Drain Maximum Voltage	20	V (**)

(\*\*) Not operative - STANDBY condition (\*\*\*) Each motor driver

#### **PINS CONNECTION**

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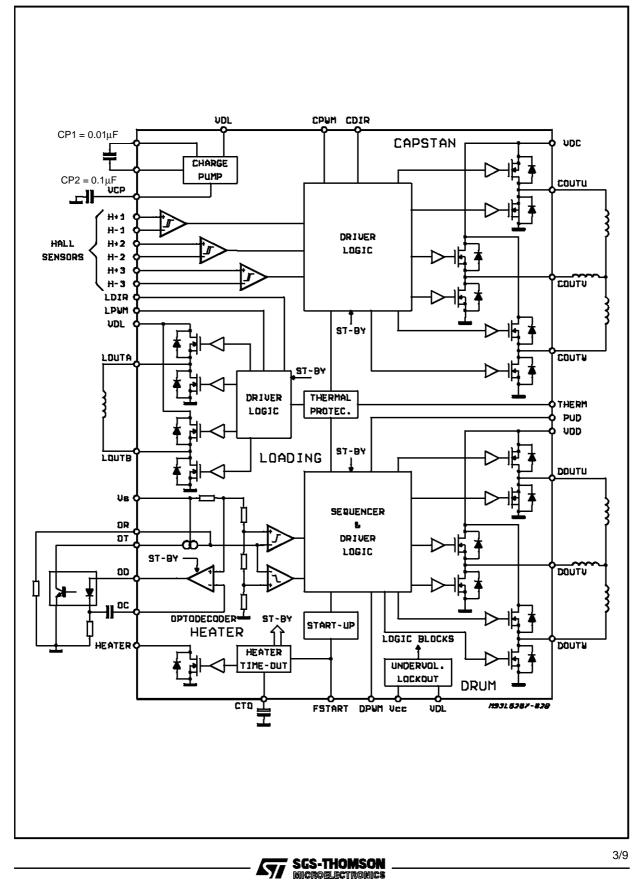
#### THERMAL DATA

Symbol	ol Parameter Value		Unit
R <sub>thj-amb</sub>	Thermal Resistance Junction to Ambient	48	°C/W
R th j-pins	Thermal Resistance Junction to Pin	15	°C/W

Note: Batwing pin.



#### **BLOCK DIAGRAM**



### PIN DESCRIPTION

СТО	Time out capacitor output
FSTART	Start-up logic signal for drum motor
THERM	Open drain thermal alarm output
CP2	Bootstrap Capacitor pin
V <sub>CP</sub> CP1	Charge pump storage capacitor pin Bootstrap Capacitor pin
HEATER	Open drain output for heater resistor
	Open drain output for boster register
	Direction logic input
Lрwм	PWM logic input.
LOUT B	Winding Output B
	Winding Output A
H3-	
H3+ H3-	Hall sensor differential input
H2+ H2-	Hall sensor differential input
H1-	
H1+	Hall sensor differential input
CDIR	Motor Direction Logic Input Signal
Срум	PWM logic pulse input. Control signal generated by μP for current regulation.
Соити	Winding Output W
	Winding Output V
Соити	Winding Output U
OR	Tacho-converter external resistor. This resistor defines the full-light current level of the tacho.
OT	Input for optocoupler transistor
00	External capacitor for tacho-converter integrator
OD	Optocoupler diode output
Pub	Logic output position feedback generated by the translator logic
Dpwm	PWM logic pulse input. Control signal generated by μP for dump motor current regulation.
Doutw	Winding Output W
Dout v	Winding Output V
Doutu	Winding Output U
DRUM MOTOR	
	d V <sub>S</sub> Power Supply must be together either at maximum or minimum value.
Sgnd	Analog ground
Vs	Analog voltage supply
GND L	Loading + Charge pump Power ground
GND R	Capstan + drum power ground
Lgnd	Logic Ground
Vcc	Logic voltage supply
VDL	Power supply voltage for loading motor and charge pump
VDC	Power supply voltage for capstan motor
	Power supply voltage for drump motor
	Power supply voltage for capstan motor



# **ELECTRICAL CHARACTERISTICS** (Tj = 0 to125°C; $V_{CC} = V_S = 5V \pm 5\%$ ; $V_{DC} = V_{DL} = V_{DD} = 10$ to 18V; unless otherwise specified.)

## **POWER SUPPLY**

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
(#)V <sub>DD</sub>	Drum Power Supply Voltage		10		18	V
(#)V <sub>DC</sub>	Capstan Power Supply Voltage		10		18	V
(#)V <sub>DL</sub>	Loading Power Supply Voltage		10		18	V
V <sub>CC</sub>	Logic Power Supply Voltage		4.5		5.5	V
Vs	Sensor Power Supply Voltage		4.75		5.25	V
V <sub>CCth</sub>	Undervoltage Threshold		3.6		4.4	V

# WARNING The functionality of the I.C. is guaranted in this voltage range. Nevertheless the specified operating voltages (VDC, VDD, VDL), must be selected according to the load characteristics. Proper cautions must be taken in the application in order to assure that the drain-source voltage across each output power transistor does not exceed 20V max.

#### LOADING MOTOR

#### ACTIVATION TRUTH TABLE

INF	TUT	OUTPUT		
LPWM LDIR		LOUTA	LOUTB	
0	0	LOW	LOW	
0	1	LOW	LOW	
1	0	HIGH	LOW	
1	1	LOW	HIGH	

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
R <sub>DSH</sub>	High Side R <sub>DSonH</sub>				2	Ω
R <sub>DSL</sub>	Low Side RDSonL				2	Ω
(*)I <sub>OL</sub>	DC Output Current				800	mA
(*)I <sub>pl</sub>	Peak Output Current	DUTY CYCLE = 10%; ton = 500ms			1	A

#### **DRUM MOTOR**

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
I <sub>cd</sub>	DC Output Current				400	mA
(*)I <sub>cdp</sub>	Peak Output Current				600	mA
(*)I <sub>pdb</sub>	Peak Output Current	DUTY CYCLE = 10%; ton = 500ms			800	mA
RDSH	High Side RDSonH				1.6	Ω
R <sub>DSL</sub>	Low Side RDSonL				1.6	Ω

#### **CAPSTAN MOTOR**

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
Ico	DC Output Current				800	mA
(*)I <sub>cop</sub>	Peak Output Current				1	Α
(*)I <sub>pob</sub>	Peak Output Current	DUTY CYCLE = 10%; ton = 1ms			1.5	A
R <sub>DSH</sub>	High Side RDSonH				1	Ω
R <sub>DSL</sub>	Low Side RDSonL				1	Ω

(\*) WARNING These current values are compatible with the structure of the IC power structure. Nevertheless the use of these current levels could produce junction temperatures that force IC outside of the operative range due to the thermal characteristics of the choosen package.



### ELECTRICAL CHARACTERISTICS (continued) DRUM TACHO CONVERTER

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
l <sub>od</sub>	Open Loop Output Current	$V_{od} = 1V; I_{oc} = 100\mu A$ (Note 1)	30		60	mA
I <sub>ot</sub>	Full Light Current Range		0.5		3	mA
l <sub>oc</sub>	Sink Current	$V_{or} = 0; I_{od} = 0$	0.2		0.5	μA
l <sub>ot</sub> vs l <sub>or</sub>	Mismatch			5	10	%
V <sub>ref</sub>	Opto Resistor Reference	Vs = 4.75V	3.36		3.72	V
	Voltage	Vs = 5V	3.54		3.91	V
		Vs = 5.25V	3.72		4.11	V
V <sub>oc</sub>	Open Loop Opto Capacitor Voltage	$V_{OD} = 1V$ see Fig. 1 $V_{S} = 4.75V$ $V_{S} = 5V$ $V_{S} = 5.25V$	2.75			V
V <sub>thr1</sub>	Clock Threshold Voltage	Vs = 4.75V	2.19		2.42	V
		$V_{S} = 5V$	2.30		2.54	V
		Vs = 5.25V	2.42		2.67	V
V <sub>thr2</sub>	Reset Threshold Voltage	Vs = 4.75V	0.30		0.33	V
		Vs = 5V	0.32		0.35	V
		Vs = 5.25V	0.33		0.37	V
t <sub>pud</sub>	μP Syncro Pulse Duration		1		3	μs
I <sub>pud1</sub>	Open Drain Sink Current	Vo = 0.4V	5			mA

Note 1: The suggested  $C_{\text{opt}}$  external capacitor value is 5µF (±5%)

#### HALL COMPARATOR

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
Vin	Input Voltage Range		0.5		2.7	V
l <sub>b</sub>	Input Bias Current				1	μA
V <sub>of</sub>	Input Offset Voltage				8	mV
V <sub>hy</sub>	Switchable Hysteresys	Vref = 1.5V;	10		40	mV

#### THERMAL PROTECTION

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
I <sub>therm</sub>	Open Drain Sink Current	Vout = 0.4V (see note 1)	5			mA
Ts	Shutdown Temperature		155	170	185	°C
T <sub>sdh</sub>	Shutdown Hysteresis			60		°C
T <sub>al1</sub>	Early Warning Temperature			Ts -40		°C
T <sub>al2</sub>	Last Warning Temperature	(see note 2)		Ts -20		°C

NOTE 1: Therm output stage is on in the normal temperature range

NOTE 2: In the Tal-TII temperature range therm signal follows the inverted Fstart signal. After TII temperature this output is always in high impedance. If thermal shutdown is reached this pin will remain in this state until the shutdown hysteresys will be recovered.

#### HEATER

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
R <sub>dsheat</sub>	Heater R <sub>DSon</sub>				3	ohm
V <sub>heat</sub>	Heater Voltage				18	V



#### ELECTRICAL CHARACTERISTICS (continued.)

#### LOGIC LEVELS FOR DIGITAL INPUTS (CPWM, CDIR, DPWM, FSTART, LPWM, LDIR)

A pull up resistor Ri is connected between the  $C_{\text{DIR}},\,F_{\text{START}},\,L_{\text{PWM}},\,L_{\text{DIR}}$  inputs pads;  $C_{\text{PWM}}$  and  $D_{\text{PWM}}$  are left unconnected.

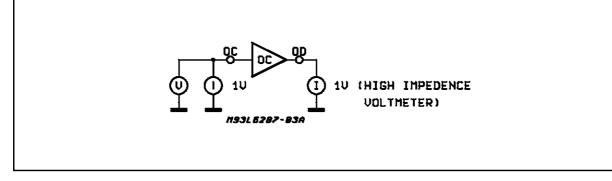
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
Vil	Input Low Voltage				0.8	V
Vih	Input High Voltage		2			V
Ri	Pull Up Resistor		3.5		10.5	Kohm

#### TIME OUT STAGE

Symbo	Parameter	Test Condition	Min.	Тур.	Max.	Unit
I <sub>cto</sub>	Time Out Output Current	(Note 1)	5		20	uA

Note 1: The suggested external capacitor value is  $C_{to}$  = 1µF (±20% max) for  $f_{\text{START}}$  = 20KHz.

#### Figure 1: Optocircuit Open Loop OC Voltage.

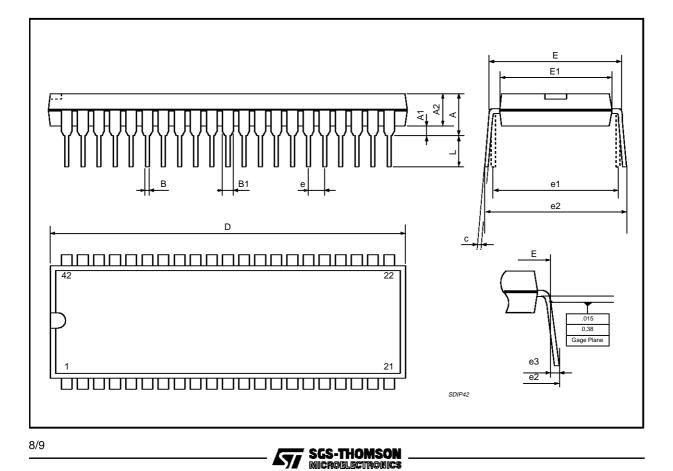




#### L6287

DIM.		mm		inch		
Diwi.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А			5.08			0.20
A1	0.51			0.020		
A2	3.05	3.81	4.57	0.120	0.150	0.180
В	0.36	0.46	0.56	0.0142	0.0181	0.0220
B1	0.76	1.02	1.14	0.030	0.040	0.045
с	0.23	0.25	0.38	0.0090	0.0098	0.0150
D	37.85	38.10	38.35	1.490	1.50	1.510
E	15.24		16.00	0.60		0.629
E1	12.70	13.72	14.48	0.50	0.540	0.570
е		1.778			0.070	
e1		15.24			'0.60	
e2			18.54			0.730
e3			1.52			0.060
L	2.54	3.30	3.56	0.10	0.130	0.140

#### SDIP42 PACKAGE MECHANICAL DATA



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